



## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	
Sung-Chan PARK et al.	) Group Art Unit: 2813
Application No.: 09/998,303	) Examiner: Nguyen, Thanh T.
Filed: December 3, 2001	)
For: METHOD FOR FORMING CONTACT HOLE AND SPACER OF SEMICONDUCTOR DEVICE	) Confirmation No.: 4821

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## **AMENDMENT**

In reply to the Office Action mailed on September 27, 2004, please amend this application as follows. The period for responding to the Office Action has been extended through January 27, 2005, by a Petition for Extension of Time and payment of requisite fees filed concurrently herewith.

Amendments to the Claims are reflected in the listing of claims beginning on page 2 of this paper.

Remarks follow the amendment to the Claims and begin on page 4 of this paper.